

CTL SH1-50M832DS
SURFACE MOUNT
DUAL, HIGH CURRENT
LOW V_F
SILICON SCHOTTKY RECTIFIERS



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CTL SH1-50M832DS Dual, Isolated, Low V_F Silicon Schottky rectifiers are designed for applications where small size and operational efficiency are the prime requirements. With a maximum power dissipation of 1.65W, and a very small package footprint (approximately equal to the SOT-23), this leadless package design is capable of dissipating up to 4 times the power of similar devices in comparable sized surface mount packages.



APPLICATIONS:

- DC - DC Converters
- Reverse Battery Protection
- Battery Powered Portable Equipment

MAXIMUM RATINGS: (T_A=25°C)

Peak Repetitive Reverse Voltage

Continuous Forward Current

Peak Repetitive Forward Current, t_p≤1.0ms

Peak Forward Surge Current, t_p=8.0ms

Power Dissipation (Note 1)

Operating and Storage Junction Temperature

Thermal Resistance (Note 1)

SYMBOL		UNITS
V _{RRM}	50	V
I _F	1.0	A
I _{FRM}	3.5	A
I _{FSM}	10	A
P _D	1.65	W
T _J , T _{stg}	-65 to +150	°C
Θ _{JA}	75.8	°C/W

ELECTRICAL CHARACTERISTICS PER DIODE: (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I _R	V _R =5.0V			10	µA
I _R	V _R =8.0V			20	µA
I _R	V _R =15V			50	µA
I _R	V _R =50V			0.5	mA
I _R	V _R =50V, T _A =100°C			50	mA
BV _R	I _R =100µA	50			V
V _F	I _F =10mA			0.29	V
V _F	I _F =100mA			0.36	V
V _F	I _F =500mA			0.45	V
V _F	I _F =1.0A			0.55	V
C _J	V _R =4.0V, f=1.0MHz		50		pF

Notes: (1) FR-4 Epoxy PC Board with copper mounting pad area of 54mm²

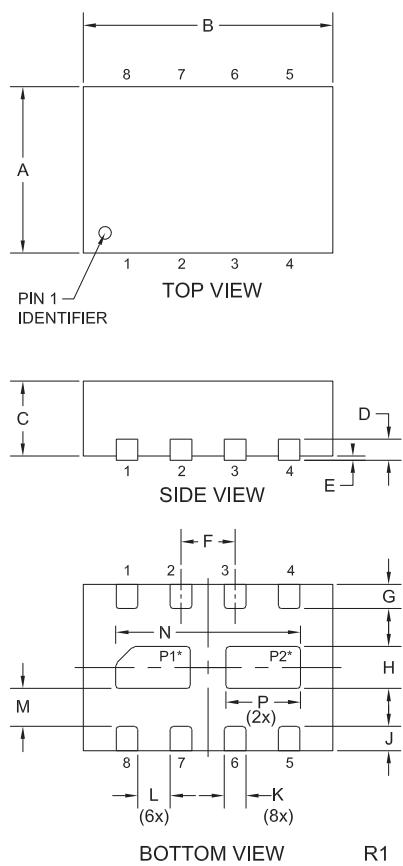
R1 (23-September 2011)

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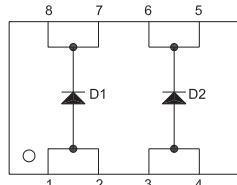


TLM832DS CASE - MECHANICAL OUTLINE



* Exposed pad P1 common to pins 7 and 8
Exposed pad P2 common to pins 5 and 6

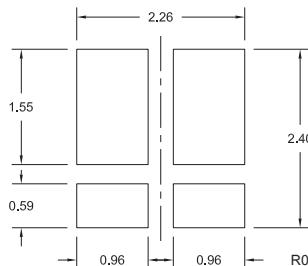
PIN CONFIGURATION



SYMBOL	DIMENSIONS		INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX	MIN	MAX
A	0.077	0.081	1.95	2.05		
B	0.116	0.120	2.95	3.05		
C	0.031	0.039	0.80	1.00		
D	0.006	0.010	0.16	0.25		
E	0.000	0.002	0.00	0.05		
F		0.026			0.65	
G	0.008	0.016	0.19	0.40		
H	0.014	0.024	0.35	0.61		
J	0.008	0.016	0.19	0.40		
K	0.008	0.012	0.21	0.31		
L	0.013	0.017	0.34	0.44		
M	0.006	--	0.15	--		
N		0.087			2.22	
P	0.029	0.039	0.74	1.00		

TLM832DS (REV:R1)

**SUGGESTED MOUNTING PADS
For Maximum Power Dissipation**
(Dimensions in mm)



LEAD CODE:

- | | |
|-------------|---------------|
| 1) Anode D1 | 5) Cathode D2 |
| 2) Anode D1 | 6) Cathode D2 |
| 3) Anode D2 | 7) Cathode D1 |
| 4) Anode D2 | 8) Cathode D1 |

MARKING CODE: CFX

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